

LL4154

Vishay Semiconductors

Small Signal Fast Switching Diode

Features

- Silicon epitaxial planar diodes
- Electrical data identical with the device 1N4154
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

Applications

• Extreme fast switches



ROHS COMPLIANT



Mechanical Data

Case: MiniMELF SOD-80 Weight: approx. 31 mg Cathode band color: black Packaging codes/options: GS18/10 k per 13" reel (8 mm tape), 10 k/box GS08/2.5 k per 7" reel (8 mm tape), 12.5 k/box

Parts Table

Part	Ordering code	Type Marking	Remarks
LL4154	LL4154-GS18 or LL4154-GS08	-	Tape and Reel

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Repetitive peak reverse voltage		V _{RRM}	35	V
Reverse voltage		V _R	25	V
Peak forward surge current	t _p = 1 μs	I _{FSM}	2	А
Repetitive peak forward current		I _{FRM}	500	mA
Forward continuous current		١ _F	300	mA
Average forward current	V _R = 0	I _{FAV}	150	mA
Power dissipation		P _{tot}	500	mW

Thermal Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air	On PC board 50 mm x 50 mm x 1.6 mm	R _{thJA}	500	K/W
Junction temperature		Тj	175	°C
Storage temperature range		T _{stg}	- 65 to + 175	°C

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Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min.	Тур.	Max.	Unit
Forward voltage	I _F = 30 mA	V _F			1000	mV
Reverse current	V _R = 25 V	I _R			100	nA
	V _R = 25 V, T _j = 150 °C	I _R			100	μA
Breakdown voltage	$I_R = 5 \ \mu A, \ t_p/T = 0.01,$ $t_p = 0.3 \ ms$	V _(BR)	35			v
Diode capacitance	V _R = 0, f = 1 MHz, V _{HF} = 50 mV	CD			4	pF
Reverse recovery time	I _F = I _R = 10 mA, i _R = 1mA	t _{rr}			4	ns
	$I_F = 10$ mA, $V_R = 6$ V, $i_R = 0.1$ x I_R , $R_L = 100$ Ω	t _{rr}			2	ns

Typical Characteristics

 $T_{amb} = 25 \text{ °C}$, unless otherwise specified

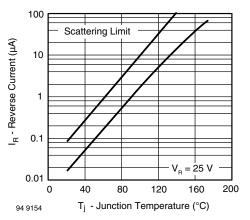


Figure 1. Reverse Current vs. Junction Temperature

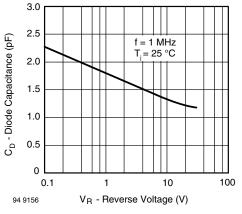


Figure 3. Diode Capacitance vs. Reverse Voltage

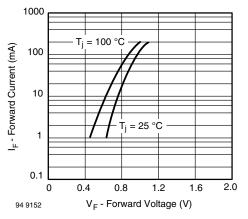
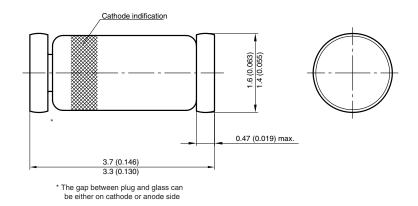


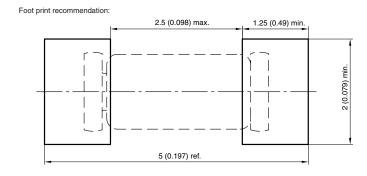
Figure 2. Forward Current vs. Forward Voltage



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Package Dimensions in millimeters (inches): MiniMELF SOD-80





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